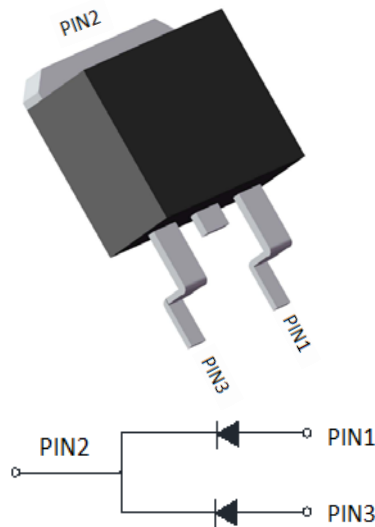


Ultra-Fast Recovery Rectifier Diodes



Features

- High frequency operation
- High surge forward current capability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Adopt GPP chip
- Passivation for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package:** TO-263
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

■Maximum Ratings (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MURB1660CT-B1-0000S
Device Marking Code			MURB1660CT
Repetitive Peak Reverse Voltage	VRRM	V	600
Average Rectified Output Current @60Hz half sine-wave, R-load, T _c (FIG.1)	I _o	A	16
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, T _a =25°C	I _{FSM}	A	125
Current Squared Time @1ms≤t<8.3ms T _j =25°C	I ² t	A ² s	65
Storage Temperature	T _{stg}	°C	-55 ~ +150
Junction Temperature	T _j	°C	-55 ~ +150

■Electrical Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MURB1660CT-B1-0000S
Maximum instantaneous forward voltage drop per diode	V _{FM}	V	I _{FM} =8.0A	1.7
Maximum DC reverse current at rated DC blocking voltage per diode	I _{RRM1}	μA	V _{RM} =V _{VRRM} T _a =25°C	10
	I _{RRM2}		V _{RM} =V _{VRRM} T _a =125°C	500
Reverse Recovery Time	T _{rr}	ns	I _F =0.5A I _{RM} =1A I _{RR} =0.25A	50

■Thermal Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MURB1660CT-B1-0000S
Thermal Resistance Between junction and case	R _{θJ-C}	°C/W	2.0



MURB1660CT-B1-0000S

Ordering Information (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MURB1660CT-B1-0000S	Approximate 1.48	50	1000	5000	Tube

Characteristics (Typical)

FIG1: I_o -Tc Curve

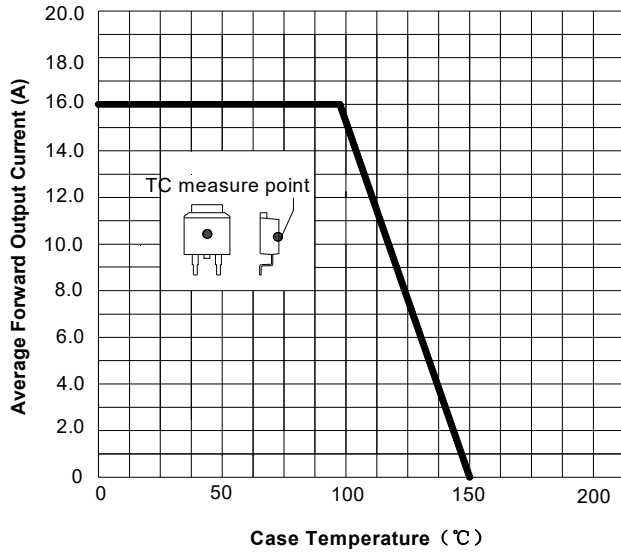


FIG2: Surge Forward Current Capability

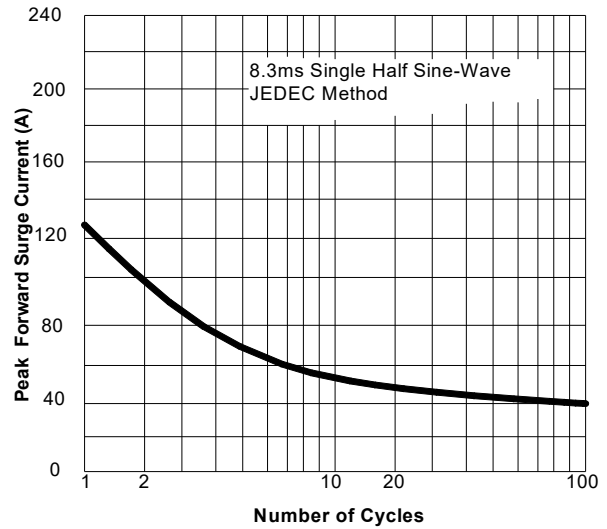


FIG3: Forward Voltage

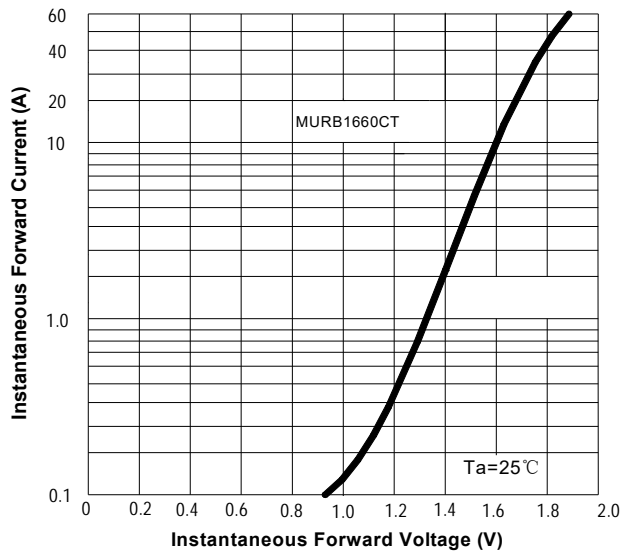


FIG4: Typical Reverse Characteristics

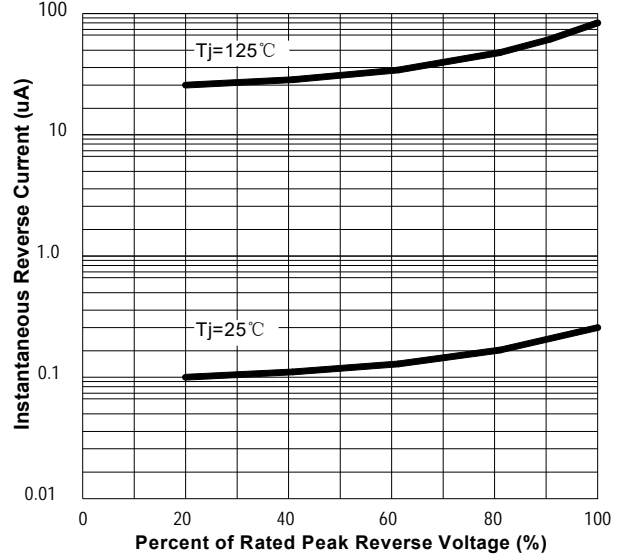
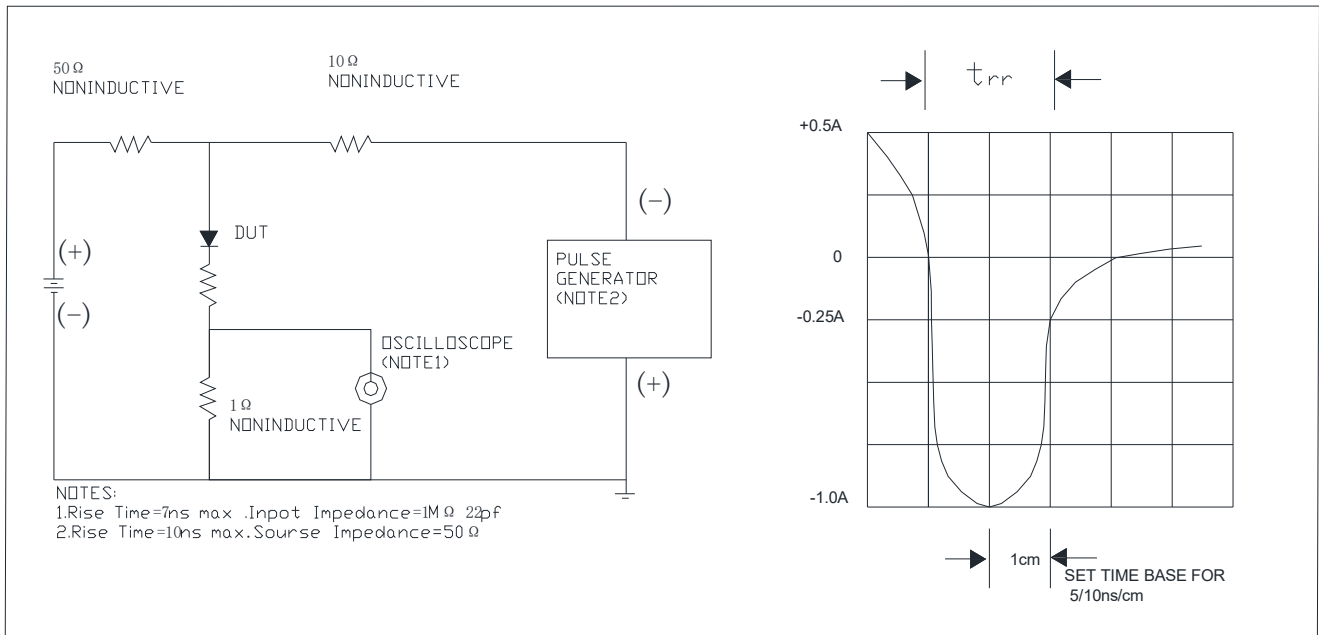
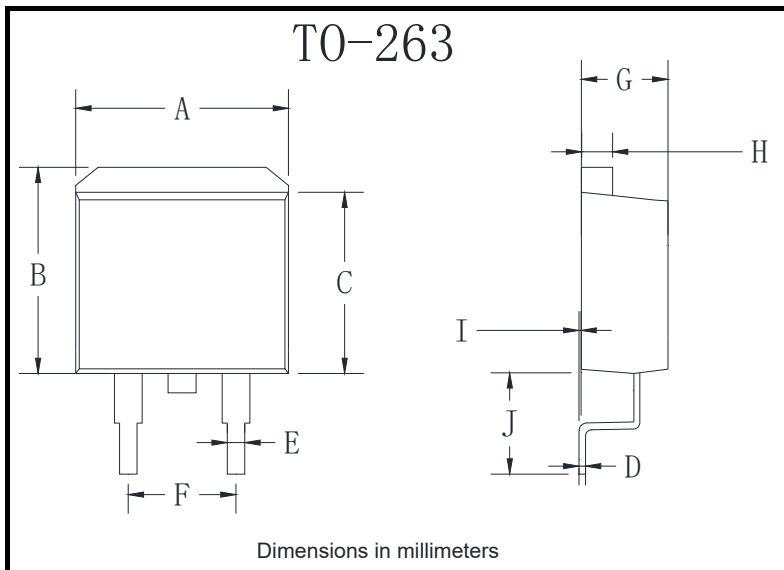


FIG.5 Diagram of circuit and Testing wave form of reverse recovery time



■ Outline Dimensions



TO-263		
Dim	Min	Max
A	9.5	11.5
B	9.7	10.5
C	8.4	9.0
D	0.28	0.64
E	0.68	0.94
F	4.55	5.6
G	4.04	5.10
H	1.14	1.4
I	0	0.2
J	4.9	6.05



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